

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1
 Stylesheet Version v1.2

EPAS ID: PAT6590535

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| SUBMISSION TYPE: | NEW ASSIGNMENT |
| NATURE OF CONVEYANCE: | ASSIGNMENT |
| CONVEYING PARTY DATA | |
| Name | Execution Date |
| YA-YI TSAI | 03/16/2018 |
| YI-HSUAN HSIAO | 03/25/2018 |
| SHU-YUAN KU | 03/16/2018 |
| RYAN CHIA-JEN CHEN | 03/16/2018 |
| MING-CHING CHANG | 03/16/2018 |
| RECEIVING PARTY DATA | |
| Name: | TAIWAN SEMICONDUCTOR MANUFACTURING CO., LTD. |
| Street Address: | 8, LI-HSIN RD. 6 |
| Internal Address: | HSINCHU SCIENCE PARK |
| City: | HSINCHU |
| State/Country: | TAIWAN |
| Postal Code: | 300-78 |
| PROPERTY NUMBERS Total: 1 | |
| Property Type | Number |
| Application Number: | 17195189 |
| CORRESPONDENCE DATA | |
| Fax Number: | (214)200-0853 |
| <i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i> | |
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| Correspondent Name: | HAYNES AND BOONE, LLP (24061) IP SECTION |
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| ATTORNEY DOCKET NUMBER: | 2017-1478/24061.3633US03 |
| NAME OF SUBMITTER: | MARCY OGADO |
| SIGNATURE: | /Marcy Ogado/ |
| DATE SIGNED: | 03/09/2021 |

Total Attachments: 4

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np-22412-0-US-B7 TL (S)

Attorney Docket No. P20171478US00 / 24061.3633US01
Customer No. 42717**ASSIGNMENT**

WHEREAS, we,

- | | | | |
|-----|--------------------|----|-------------|
| (1) | Ya-Yi Tsai | of | Hsinchu, TW |
| (2) | Yi-Hsuan Hsiao | of | Hsinchu, TW |
| (3) | Shu-Yuan Ku | of | Hsinchu, TW |
| (4) | Ryan Chia-Jen Chen | of | Hsinchu, TW |
| (5) | Ming-Ching Chang | of | Hsinchu, TW |

have invented certain improvements in

**RESIDUE-FREE METAL GATE CUTTING FOR
FIN-LIKE FIELD EFFECT TRANSISTOR**

for which we have executed an application for Letters Patent of the United States of America,

 X of even date filed herewith; and
 filed on 03/28/2018 and assigned application number 15/938,812; and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Co., Ltd., ("TSMC"), 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78, Republic of China, is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to

issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name: Ya-Yi Tsai

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

Dated: _____

Inventor Signature

Inventor Name: Yi-Hsuan Hsiao

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

Dated: 2018. 3. 25

Yi-Hsuan Hsiao

Inventor Signature

Inventor Name: Shu-Yuan Ku

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

Dated: _____

Inventor Signature

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Inventor Name: Ya-Yi Tsai

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

Dated: 03-16-2018

Yayī Tsai

Inventor Signature

Inventor Name: Yi-Hsuan Hsiao

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

Dated: _____

Inventor Signature

Inventor Name: Shu-Yuan Ku

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

Dated: 03-16-2018

Shu Yuan Ku

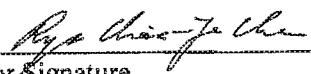
Inventor Signature

Attorney Docket No. P20171478US00 / 24061.3633US01
Customer No. 42717

Inventor Name: Ryan Chia-Jen Chen

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

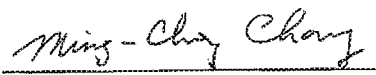
Dated: 03-16-2018


Inventor Signature

Inventor Name: Ming-Ching Chang

Address: 8, Li-Hsin Rd. 6, Hsinchu Science Park, Hsinchu, Taiwan 300-78

Dated: 03-16-2018


Inventor Signature